



1762  
JIFW

Attorney's Docket No. 5308-157IP2

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Das et al.

Confirmation No.: 3570

Serial No.: 10/045,542

Group Art Unit: 1762

Filed: October 26, 2001

Examiner: Michael. E. Barr

For: METHOD OF FABRICATING AN OXIDE LAYER ON A SILICON CARBIDE  
LAYER UTILIZING AN ANNEAL IN A HYDROGEN ENVIRONMENT

Date: July 27, 2004

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**SUPPLEMENTAL AMENDMENT**

Sir:

Applicants provide the present Supplemental Amendment to clarify statements made regarding the Xu reference in Applicants previous responses.

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 6 of this paper.